

Support Information

Dipole orientation-induced Interfacial energy level alignment difference in 2D

perovskite passivated 3D perovskite by in-situ investigation

Ruifeng Zheng¹⁺, Jielei Li¹⁺, Shengwen Li^{1*}, Bingchen He¹, Shi Chen^{1*}

¹Institute of Applied Physics and Materials Engineering, University of Macau, Macau
SAR 999078, P. R. China.

Corresponding authors: shengwenli@um.edu.mo, shichen@um.edu.mo

+ These authors contributed equally.

Keywords: Interfacial energetics; 2D perovskite; passivation; in-situ; perovskite solar
cell.

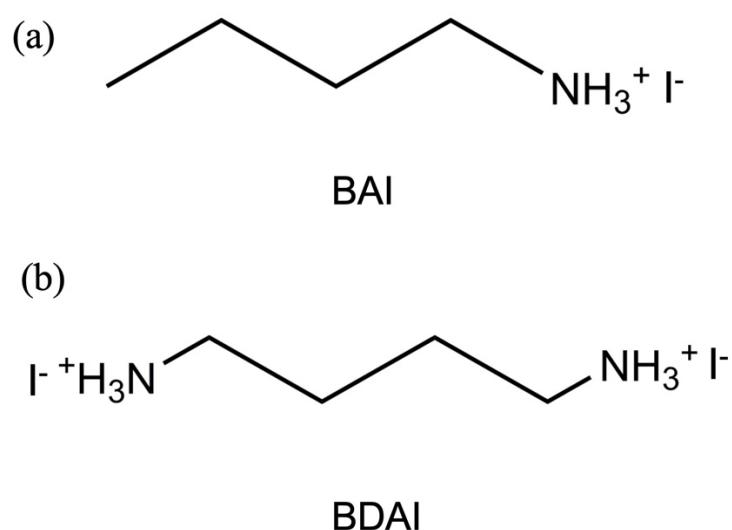


Figure S1. Chemical structures of (a) BAI and (b) BDAI

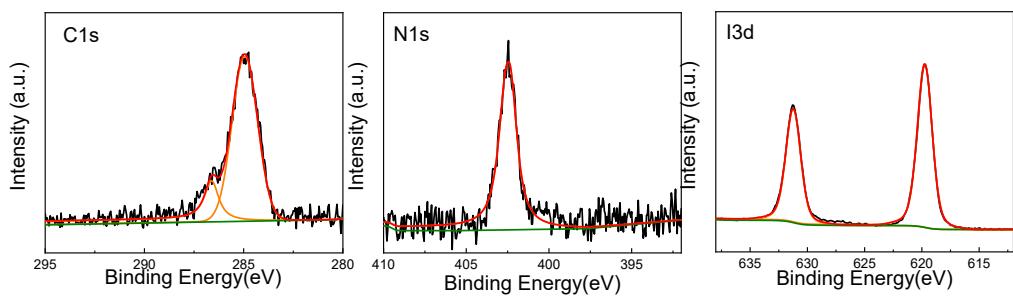


Figure S2. XPS spectra of BAI grown on ITO substrate.

| | C-C | C-N | N1s | I3d |
|------------|------|------|------|-------|
| Area | 2907 | 987 | 1748 | 25758 |
| Normalized | 9820 | 3334 | 3665 | 4151 |
| Ratio | 2.95 | 1.00 | 1.10 | 1.25 |

Table S1. The calculated content ratio of BAI grown on ITO substrate.

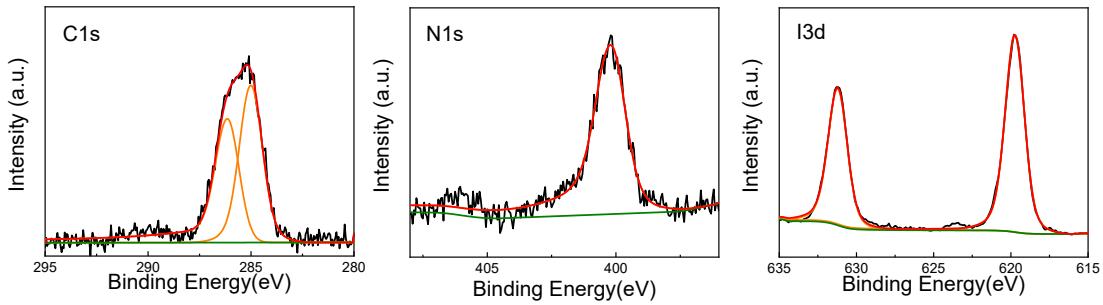


Figure S3. XPS spectra of BDAI grown on ITO substrate.

| | C-C | C-N | N1s | I3d |
|------------|------------|------------|------------|------------|
| Area | 2800 | 2796 | 4359 | 73766 |
| Normalized | 9459 | 9444 | 9139 | 11886 |
| Ratio | 1.00 | 1.00 | 0.97 | 1.26 |

Table S2. The calculated content ratio of BDAI grown on ITO substrate.

| | C-N | C-C | N |
|----------|-----|------|------|
| pristine | 1 | 0.81 | 0.91 |
| 0.5nm | 1 | 1.08 | 1.04 |
| 1nm | 1 | 1.08 | 1.01 |
| 2nm | 1 | 1.13 | 0.99 |
| 4nm | 1 | 1.21 | 0.91 |
| 6nm | 1 | 1.27 | 0.88 |
| 8nm | 1 | 1.30 | 0.85 |
| 16nm | 1 | 1.72 | 0.89 |
| 32nm | 1 | 2.70 | 0.91 |

Table S3. The calculated content ratio of BAI grown on PSK substrate.

| | C-N | C-C | N |
|----------|-----|------|------|
| pristine | 1 | 1.35 | 0.96 |
| 1nm | 1 | 1.16 | 0.89 |
| 2nm | 1 | 1.17 | 0.87 |
| 4nm | 1 | 1.19 | 0.87 |
| 8nm | 1 | 1.19 | 0.85 |
| 20nm | 1 | 1.25 | 0.86 |

Table S4. The calculated content ratio of BDAI grown on PSK substrate.

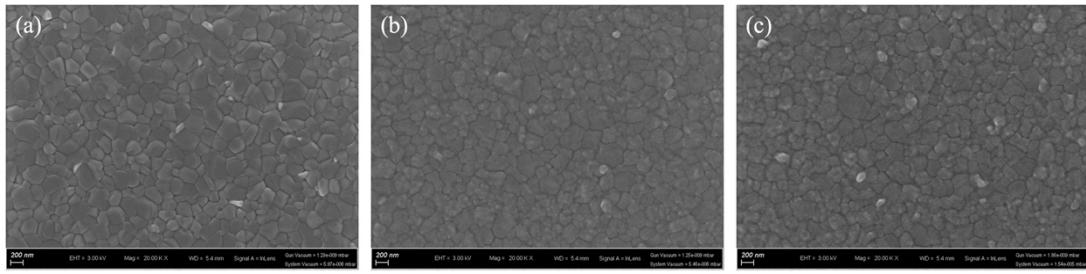


Figure S4 SEM images of (a) pristine perovskite film and perovskite films deposited with (b) BAI and (c) BDAI

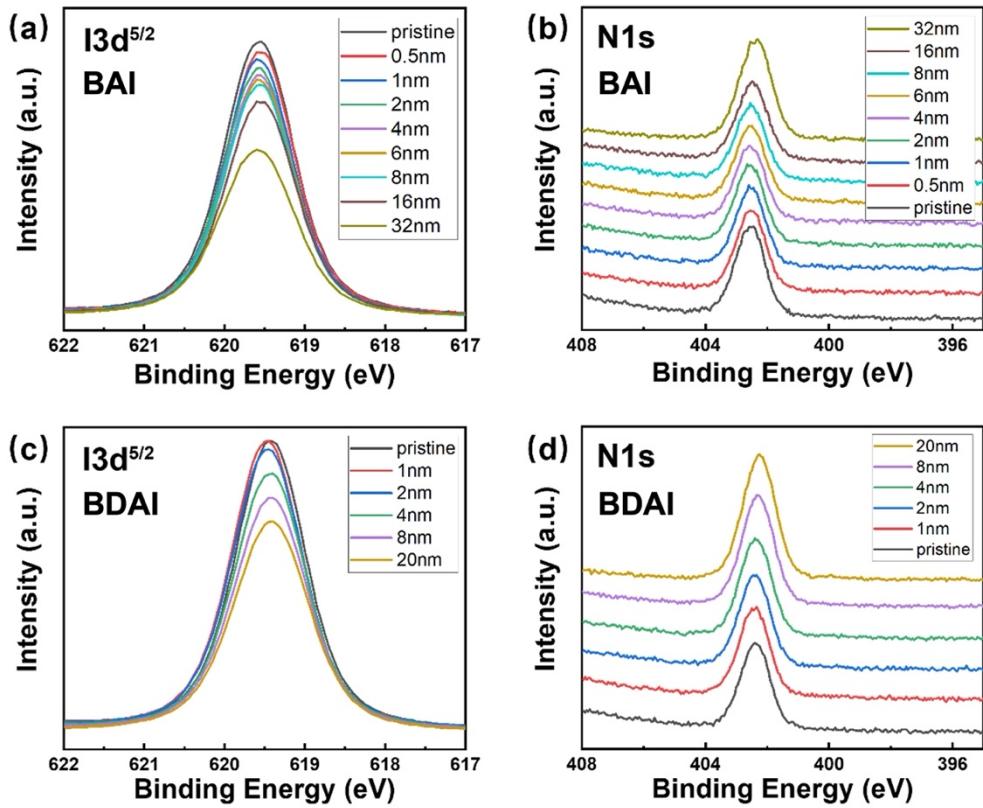


Figure S5. (a,b) XPS images of BAI grown on perovskite substrates; (c,d) XPS images of BDAI grown on perovskite substrates.

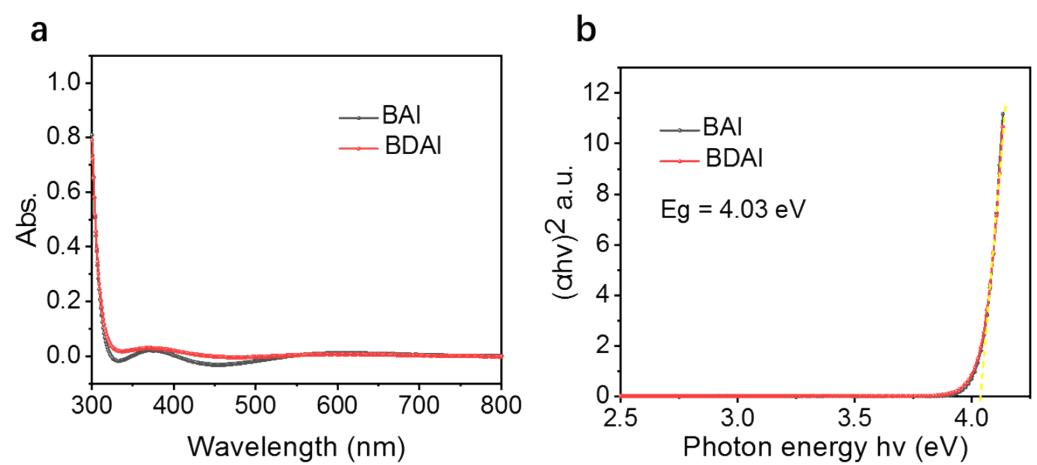


Figure S6, (a) UV-Vis measurement of BAI and BDAI molecular thin films on quartz;
(b) calculated band gap for both molecules.

| Measurements(nm) | Calculated(nm) |
|------------------|----------------|
| 0 | 0 |
| 0.5 | 2.03 |
| 1 | 1.82 |
| 2 | 3.10 |
| 4 | 5.94 |
| 6 | 7.66 |
| 8 | 9.32 |
| 16 | 14.24 |

Table S5. Comparison of film thickness of BAI on PSK

| Measurements(nm) | Calculated(nm) |
|------------------|----------------|
| 0 | 0 |
| 1 | 0.13 |
| 2 | 1.21 |
| 4 | 4.48 |
| 8 | 9.56 |
| 20 | 19.18 |

Table S6. Comparison of film thickness of BDAI on PSK

| Molecule | Structure | Perovskite | V _{OC} (V) | J _{SC} (mA/cm ²) | FF (%) | PCE (%) | Ref. |
|----------|-----------|--|------------------------|--|-----------|------------|---------------|
| BAI | regular | FAPbI ₃ | 1.16 | 24.95 | 81.23 | 23.46 | ¹ |
| BAI | regular | Cs _{0.07} Rb _{0.03} FA _{0.765} MA _{0.135} PbI _{2.55} Br _{0.45} | 1.20 | 24.19 | 77.56 | 22.50 | ² |
| BAI | regular | (FAPbI ₃) _{0.95} (MAPbBr ₃) _{0.05} | 1.15 | 22.69 | 78.90 | 20.67 | ³ |
| BAI | regular | MA _{0.1} FA _{0.9} PbI _{2.9} Br _{0.1} | 1.15 | 24.93 | 76.49 | 22.01 | ⁴ |
| BAI | regular | (FAPbI ₃) _{0.95} (MAPbBr ₃) _{0.05} | 1.11 | 23.99 | 81.70 | 21.71 | ⁵ |
| BAI | inverted | (AA) ₂ MA ₄ Pb ₃ I ₁₆ | 1.19 | 18.45 | 79.20 | 17.39 | ⁶ |
| BAI | inverted | FA _{0.25} MA _{0.75} PbI ₃ | 1.05 | 24.32 | 79.28 | 20.27 | ⁷ |
| BAI | regular | FAPbI ₃ | 1.18 | 24.72 | 79.27 | 23.13 | ⁸ |
| BAI | regular | Cs _{0.05} MA _{0.05} FA _{0.9} PbI ₃ | 1.16 | 26.01 | 83.90 | 25.32 | ⁹ |
| BAI | regular | CsPbI ₃ | 1.23 | 20.25 | 81.50 | 20.23 | ¹⁰ |
| BAI | inverted | Cs _{0.05} (FA _{0.92} MA _{0.08}) _{0.95} Pb (I _{0.92} Br _{0.08}) ₃ | 1.15 | 22.30 | 80.70 | 20.70 | ¹¹ |
| BDAI | inverted | Cs _{0.15} FA _{0.85} Pb(I _{0.95} Br _{0.05}) ₃ | 1.15 | 24.51 | 82.10 | 23.10 | ¹² |
| BDAI | inverted | (Cs _{0.05} MA _{0.16} FA _{0.79})Pb (I _{0.84} Br _{0.16}) ₃ | 0.99 | 26.92 | 78.87 | 20.99 | ¹³ |
| BDAI | inverted | (AA) ₂ MA ₄ Pb ₃ I ₁₆ | 1.24 | 18.69 | 79.13 | 18.34 | ⁶ |
| BDAI | inverted | (CsPbI ₃) _{0.05} (FA _{0.85} MA _{0.15} Pb(I _{0.85} Br _{0.15}) ₃) _{0.95} | 1.21 | 22.59 | 81.63 | 22.31 | ¹⁴ |
| BDAI | inverted | Cs _{0.1} MA _{0.09} FA _{0.81} Pb Cl _{0.14} I _{2.86} | 1.04 | 24.50 | 79.90 | 20.50 | ¹⁵ |
| BDAI | regular | Cs _{0.05} (FA _{0.83} MA _{0.17}) _{0.95} Pb (I _{0.83} Br _{0.17}) ₃ | 1.13 | 24.10 | 74.60 | 20.32 | ¹⁶ |

Table S7. The device structure and photoelectric properties of PSCs passivated with BAI and BDAI in recent years.

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